




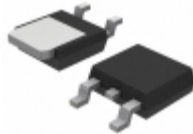

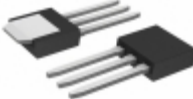
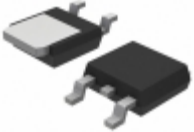
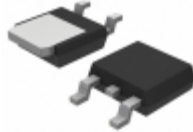
	<h2 style="color: red;">NTD24N06L-1G</h2>
	<p>Hersteller-Teilenummer: NTD24N06L-1G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 60V 24A IPAK</p> <p>Datenblätter:  NTD24N06L-1G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 5000 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTD24N06L-1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 60V 24A IPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	5000 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	I-Pak
Verlustleistung (max)	1.36W (Ta), 62.5W (Tj)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	24A (Ta)
Rds On (Max) @ Id, Vgs	45 mOhm @ 10A, 5V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	32nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	1140pF @ 25V
Verpackung	Tube





























NTD24N06L-1G ist neu im Original, Suche NTD24N06L-1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD24N06L-1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD24N06L-1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTD24N06T4 ON NTD24N06T4 ON</p>	 <p>NTD24N06-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 24A IPAK</p>	 <p>NTD24N06L4T O NTD24N06L4T O</p>	 <p>NTD24N06LT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 24A DPAK</p>
 <p>NTD24N06LT4 O NTD24N06LT4 O</p>	 <p>NTD24N06-001 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 24A IPAK</p>	 <p>NTD24N06LG AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 24A DPAK</p>	 <p>NTD24N06L AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 24A DPAK</p>

heiße Teile

Mehr

 NTD20N06LG	 NTD20N06LT4	 NTD20N06LT4G	 NTD20N06T4G	 NTD20N06V
 NTD20P03	 NTD20P03HDLT4G	 NTD20P06HCT4G	 NTD20P06HD	 NTD20P06HDLT4
 NTD20P06HL	 NTD20P06L	 NTD20P06L-001	 NTD20P06LG	 NTD20P06LT4G
 D NTD23N03R-1	 NTD23N03R-1G	 NTD23N03RG	 NTD23N03RT4	 NTD23N03RT4G
  NTD24N06	  NTD24N06-1G	 NTD24N06G	 NTD24N06L	 NTD24N06L-001
  NTD24N06L4T	  NTD24N06LG	 D NTD24N06LT4	  NTD24N06LT4G	  NTD24N06T4
  NTD24N06T4G	 D NTD25N06HL	  NTD25P03	  NTD25P03L	  NTD25P03L-1
  NTD25P03L1G	  NTD25P03LG	  NTD25P03LRLG	  NTD25P03LT4G	  NTD25P06LT4G
  NTD2955-001	  NTD2955-1	  NTD2955-1G	 D NTD2955D	  NTD2955E
  NTD2955G	  NTD2955PT4G	  NTD2955T4	  NTD2955T4G	  NTD2955V

Contact us: Info@Y-IC.com

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